NSN 5961-00-122-8678

Transistor - Page 1 of 1



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Inclosure	Material:
molocalo	materiali

Metal

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.230 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

moui

Terminal Terminal Circle Diameter:

0.100 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

18.0 breakdown voltage, collector-to-base, emitter open and 18.0 breakdown voltage, collector-to-emitter, base open and 5.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

100.00 milliamperes source cutoff current

Power Rating Per Characteristic:

3.3 watts collector power dissipation

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0